



BCM® Bus Converter BCM352x110y300B00



Isolated Fixed-Ratio DC-DC Converter

Features & Benefits

- 352V_{DC} 11V_{DC} 300W Bus Converter
- High efficiency (>95%) reduces system power consumption
- High power density (>1022W/in³) reduces power system footprint by >40%
- Contains built-in protection features:
 - Undervoltage
 - Overvoltage Lockout
 - Overcurrent Protection
 - Short Circuit Protection
 - Overtemperature Protection
- Provides enable/disable control, internal temperature monitoring
- Can be paralleled to create multi-kW arrays

Typical Applications

- High End Computing Systems
- Automated Test Equipment
- High Density Power Supplies
- Communications Systems

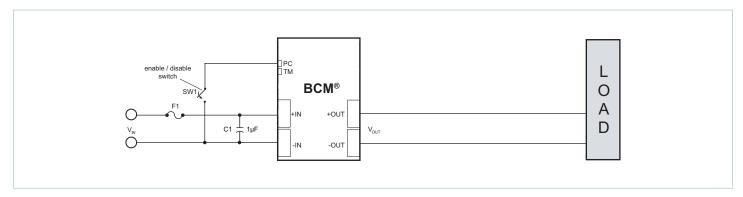
Product Ratings				
V _{IN} = 352V (330 – 365V)	P _{OUT} = up to 300W			
V _{OUT} = 11V (10.3 - 11.4V) (NO LOAD)	K = 1/32			

Product Description

The VI Chip® bus converter is a high efficiency (>95%) Sine Amplitude Converter (SAC M) operating from a 352 to 365 V_{DC} primary bus to deliver an isolated, ratiometric output voltage from 10.3 to 11.4 V_{DC}. The Sine Amplitude Converter offers a low AC impedance beyond the bandwidth of most downstream regulators; therefore capacitance normally at the load can be located at the input to the Sine Amplitude Converter. Since the transformation ratio of the BCM352x110y300B00 is 1/32, the capacitance value can be reduced by a factor of 1024x, resulting in savings of board area, materials and total system cost.

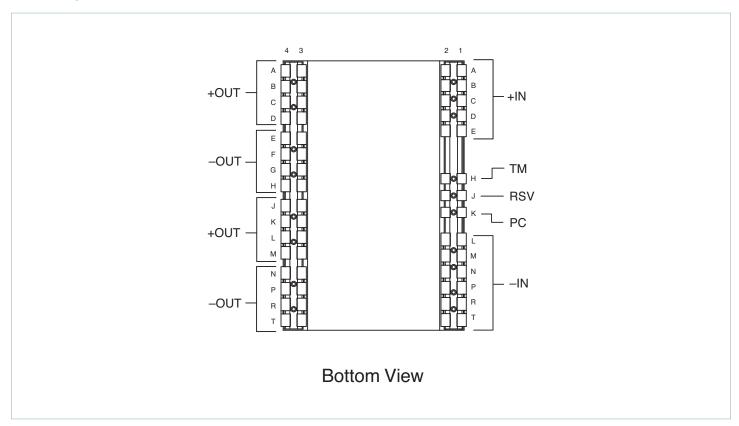
The BCM352F110y300B00 is provided in a VI Chip package compatible with standard pick-and-place and surface mount assembly processes. The co-molded VI Chip package provides enhanced thermal management due to a large thermal interface area and superior thermal conductivity. The high conversion efficiency of the BCM352x110y300B00 increases overall system efficiency and lowers operating costs compared to conventional approaches.

Typical Application





Pin Configuration



Pin Descriptions

Pin Number	Signal Name	Туре	Function
A1-E1, A2-E2	+IN	INPUT POWER	Positive input power terminal
L1-T1, L2-T2	-IN	INPUT POWER RETURN	Negative input power terminal
H1, H2	TM	OUTPUT	Temperature monitor, input side referenced signal
J1, J2	RSV	NC	No connect
K1, K2	PC	OUTPUT/INPUT	Enable and disable control, input side referenced signal
A3-D3, A4-D4, J3-M3, J4-M4	+OUT	OUTPUT POWER	Positive output power terminal
E3-H3, E4-H4, N3-T3, N4-T4	–OUT	OUTPUT POWER RETURN	Negative output power terminal

Part Ordering Information

Part Number	Package Type	Temperature Grade	Option
BCM352 F 110 T 300B 00	F = SMD	T 40 to 135%	OO Ctandard
BCM352 T 110 T 300B 00	$T = -40 \text{ to } 125^{\circ}\text{C}$		00 = Standard

Absolute Maximum Ratings

The absolute maximum ratings below are stress ratings only. Operation at or beyond these maximum ratings can cause permanent damage to the device.

Parameter	Comments	Min	Max	Unit
+IN to -IN		-1	400	V
V _{IN} Slew Rate (Operational)		-1	1	V/µs
Isolation Voltage, Input to Output			4242	V
+OUT to -OUT		-1	16	V
Output Current Transient (≤10ms, ≤10% DC)		-3	41.0	А
Output Current Average		-2	28.5	А
PC to -IN		-0.3	20	V
TM to -IN		-0.3	7	V
Operating IC Junction Temperature		-40	125	°C
Storage Temperature		-40	125	°C

Electrical Specifications

Specifications apply over all line and load conditions, unless otherwise noted; **boldface** specifications apply over the temperature range of $-40^{\circ}\text{C} \leq T_{\text{CASE}} \leq 100^{\circ}\text{C}$ (T-Grade); all other specifications are at $T_{\text{CASE}} = 25^{\circ}\text{C}$ unless otherwise noted.

Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit	
		Powertrain					
Input Voltage Range, Continuous	V _{IN_DC}		330		365	V	
Input Voltage Range, Transient	V _{IN_TRANS}	Full current or power supported, 50ms max, 10% duty cycle max	330		365	V	
Quiescent Current	IQ	Disabled, PC Low		360	432	mW	
V _{IN} to V _{OUT} Time	t _{ON1}	V _{IN} = 352V, PC floating	380	440	500	ms	
		V _{IN} = 352V, T _{CASE} = 25°C		6.4	8.7		
No-Load Power Dissipation	issination P	V _{IN} = 352V	3		15	W	
Io-Load Power Dissipation P _{NL}	' NL	$V_{IN} = 330 - 365V$, $T_{CASE} = 25^{\circ}C$			11		
		V _{IN} = 330 – 365V			15		
Inrush Current Peak	I _{INR_P}	Worse case of: V_{IN} = 365V, C_{OUT} = 1200 μ F, R_{LOAD} = 1.6 Ω		1.7	3.5	А	
DC Input Current	I _{IN_DC}	At P _{OUT} = 300W			0.9	А	
Transformation Ratio	K	$K = V_{OUT} / V_{IN}$, at no load		1/32		V/V	
Output Power (Average)	P _{OUT_AVG}	$I_{OUT_AVG} \le 28.5A$			300	W	
Output Power (Peak)	P _{OUT_PK}	10ms max, P _{OUT_AVG} ≤ 300W			450	W	
Output Current (Average)	I _{OUT_AVG}	$P_{OUT_AVG} \le 300W$			28.5	А	
Output Current (Peak)	I _{OUT_PK}	10ms max, I _{OUT_AVG} ≤ 28.5A			41.0	А	
		V _{IN} = 352V, I _{OUT} = 28.5A; T _{CASE} = 25°C	94.5	95.5			
Efficiency (Ambient)	η_{AMB}	V _{IN} = 330 – 365V, I _{OUT} = 28.5A; T _{CASE} = 25°C	94.0			%	
	7 11115	V _{IN} = 352V, I _{OUT} = 14.25A; T _{CASE} = 25°C	93.0	94.4			
Efficiency (Hot)	η_{HOT}	V _{IN} = 352V, I _{OUT} = 28.5A; T _{CASE} = 100°C	94.0	95.2		%	
Efficiency (Over Load Range)	η _{20%}	5.70A < I _{OUT} < 28.5A	90.0			%	
	R _{OUT_COLD}	I _{OUT} = 28.5A, T _{CASE} = -40°C	2.0	5.0	7.0		
Output Resistance	R _{OUT_AMB}	I _{OUT} = 28.5A, T _{CASE} = 25°C	3.8	7.7	10.7	mΩ	
	R _{OUT_HOT}	I _{OUT} = 28.5A, T _{CASE} = 100°C	7.0	10.0	13.0	_	
Switching Frequency	F _{SW}		1.85	1.95	2.05	MHz	
Output Voltage Ripple	V _{OUT_PP}	C _{OUT} = 0F, I _{OUT} = 28.5A, V _{IN} = 352V, 20MHz BW		200	400	mV	
Output Inductance (Parasitic)	L _{OUT_PAR}	Frequency up to 30MHz, Simulated J-lead model		500		рН	
Output Capacitance (Internal)	C _{OUT_INT}	Effective value at 11V _{OUT}		31.0		μF	
Output Capacitance (External)	C _{OUT_EXT}	See chart for output capacitance vs. startup load limits	0		1200	μF	



Electrical Specifications (Cont.)

Specifications apply over all line and load conditions, unless otherwise noted; **boldface** specifications apply over the temperature range of $-40^{\circ}\text{C} \leq T_{\text{CASE}} \leq 100^{\circ}\text{C}$ (T-Grade); all other specifications are at $T_{\text{CASE}} = 25^{\circ}\text{C}$ unless otherwise noted.

Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
		Protection				
Input Overvoltage Lockout Threshold	V _{IN_OVLO+}			390		V
Input Overvoltage Recovery Threshold	V _{IN_OVLO} -		366			V
Input Overvoltage Lockout Hysteresis	V _{IN_OVLO_HYST}			4		V
Overvoltage Lockout Response Time	t _{OVLO}			47		μs
Fault Recovery Time	t _{AUTO_RESTART}		380	440	500	ms
Input Undervoltage Lockout Threshold	V _{IN_UVLO} -		275	293	315	V
Input Undervoltage Recovery Threshold	V _{IN_UVLO+}		285	307	325	V
Input Undervoltage Hysteresis	V _{IN_UVLO_HYST}			14		V
Undervoltage Lockout Response Time	t _{UVLO}			47		μs
Output Overcurrent Trip Threshold	I _{OCP}		30	40	50	А
Output Overcurrent Response Time Constant	t _{OCP}	Effective internal RC filter		4.4		ms
Short Circuit Protection Trip Threshold	I _{SCP}		45			А
Short Circuit Protection Response Time	t _{SCP}			1		μs
Thermal Shut-Down Threshold	T_{J_OTP}		125			°C



Electrical Specifications (Cont.)

Specifications apply over all line and load conditions, unless otherwise noted; **boldface** specifications apply over the temperature range of $-40^{\circ}\text{C} \leq T_{\text{CASE}} \leq 100^{\circ}\text{C}$ (T-Grade); all other specifications are at $T_{\text{CASE}} = 25^{\circ}\text{C}$ unless otherwise noted.

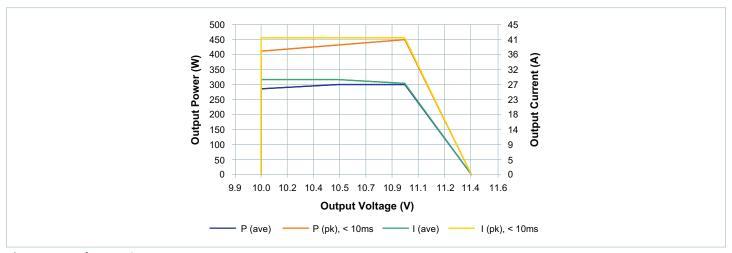


Figure 1 — Safe operating area

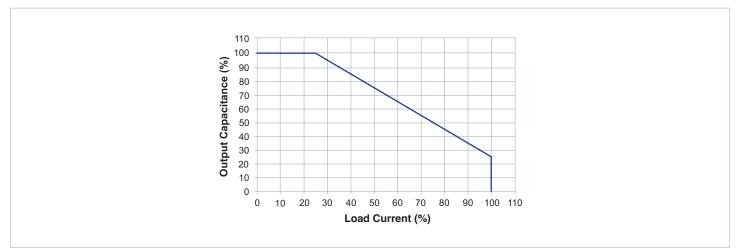


Figure 2 — Start up load current vs. output capacitance

Signal Characteristics

Specifications apply over all line and load conditions, unless otherwise noted; **boldface** specifications apply over the temperature range of $-40^{\circ}\text{C} \leq T_{\text{CASE}} \leq 100^{\circ}\text{C}$ (T-Grade); all other specifications are at $T_{\text{CASE}} = 25^{\circ}\text{C}$ unless otherwise noted.

Primary Control: PC

- The PC pin enables and disables the BCM. When held low, the BCM is disabled.
- In an array of BCM modules, PC pins should be interconnected to synchronize start up and permit start up into full load conditions.
- PC pin outputs 5V during normal operation. PC pin internal bias level drops to 2.5V during fault mode, provided V_{IN} remains in the valid range.

Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
	Regular	PC Voltage	V _{PC}		4.7	5.0	5.3	V
	Operation	PC Available Current	I _{PC_OP}		2.0	3.5	5.0	mA
Analog	nalog Standby	PC Source (Current)	I _{PC_EN}		50	100		μΑ
Output	Standby	PC Resistance (Internal)	R _{PC_INT}	Internal pull down resistor	50	150	400	kΩ
	Transition	PC Capacitance (Internal)	C _{PC_INT}				4700	рF
	Start Up	PC Load Resistance	R _{PC_S}	To permit regular operation	60			kΩ
	Start Up	PC Time to Start	t _{ON1}		380	440	500	ms
	Regular	PC Enable Threshold	V _{PC_EN}		2.0	2.5	3.0	V
	Operation	PC Disable Threshold	V_{PC_DIS}				1.95	V
Digital Input /	Standby	PC Disable Duration	t _{PC_DIS_T}	Minimum time before attempting re-enable	1			S
Output		PC Threshold Hysteresis	V _{PC_HYSTER}			50		mV
	Transition	PC Enable to V _{OUT} Time	t _{ON2}	$V_{IN} = 352V$ for at least t_{ON1} ms	50	100	150	μs
	Transition	PC Disable to Standby Time	t _{PC_DIS}			4	10	μs
		PC Fault Response Time	t _{FR_PC}	From fault to PC = 2V		100		μs

Temperature Monitor: TM

- The TM pin monitors the internal temperature of the controller IC within an accuracy of ±5°C.
- Can be used as a "Power Good" flag to verify that the BCM module is operating.
- Is used to drive the internal comparator for Overtemperature Shutdown.

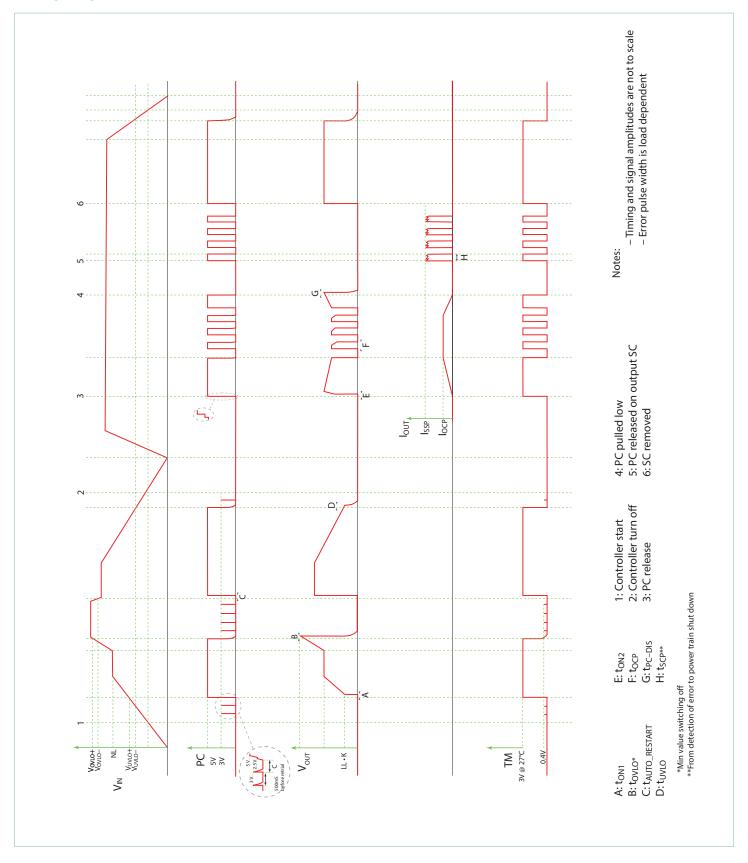
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
		TM Voltage Range	V_{TM}		2.12		4.04	V
		TM Voltage Reference	V_{TM_AMB}	T _J controller = 27°C	2.95	3.00	3.05	V
Analog Output	Regular Operation	TM Available Current	I _{TM}				100	μΑ
		TM Gain	A _{TM}			10		mV/°C
		TM Voltage Ripple	V_{TM_PP}	$C_{TM} = 0pF$, $V_{IN} = 352V$, $I_{OUT} = 28.5A$		120	200	mV
	Transition	TM Capacitance (External)	C _{TM_EXT}				50	pF
Digital		TM Fault Response Time	t _{FR_TM}	From fault to TM = 1.5V		10		μs
Input / Output	Ct a mallay	TM Voltage	V _{TM_DIS}			0		V
	Standby	TM Pull Down (Internal)	R _{TM_INT}	Internal pull-down resistor	25	40	50	kΩ

Reserved: RSV

Reserved for factory use. No connection should be made to this pin.



Timing Diagram



Application Characteristics

The following values, typical of an application environment, are collected at $T_{CASE} = 25$ °C unless otherwise noted. See associated figures for general trend data.

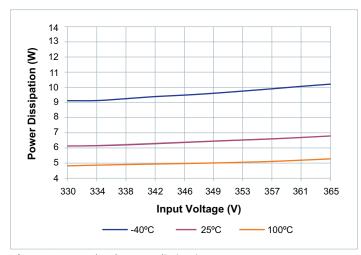


Figure 3 — No-load power dissipation vs. V_{IN}

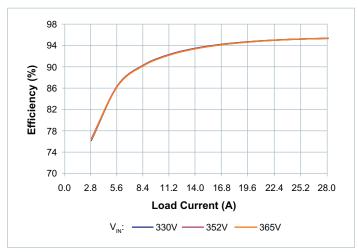


Figure 5 — Efficiency at $T_{CASE} = -40$ °C

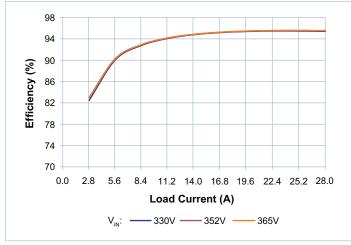


Figure 7 — Efficiency at $T_{CASE} = 25^{\circ}C$

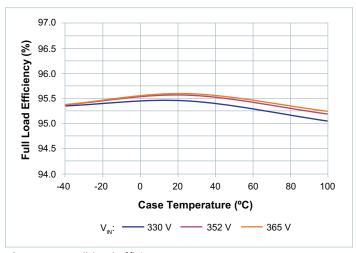


Figure 4 — Full-load efficiency vs. temperature; V_{IN}

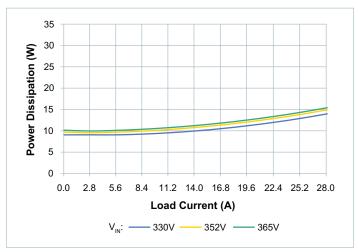


Figure 6 — Power dissipation at $T_{CASE} = -40$ °C

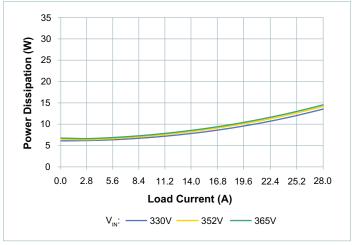


Figure 8 — Power dissipation at $T_{CASE} = 25^{\circ}C$



Application Characteristics (Cont.)

The following values, typical of an application environment, are collected at $T_{CASE} = 25$ °C unless otherwise noted. See associated figures for general trend data.

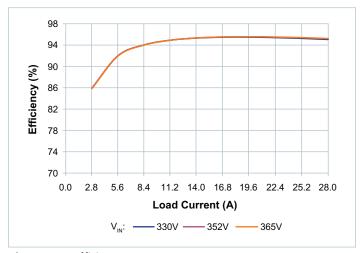


Figure 9 — Efficiency at $T_{CASE} = 100^{\circ}C$

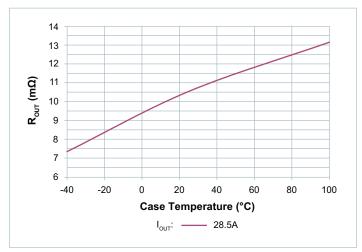


Figure 11 — R_{OUT} vs. temperature; nominal input

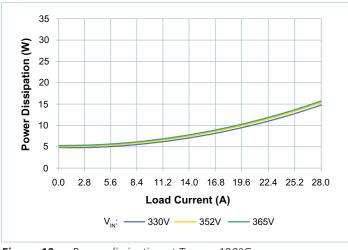


Figure 10 — Power dissipation at $T_{CASE} = 100^{\circ}C$

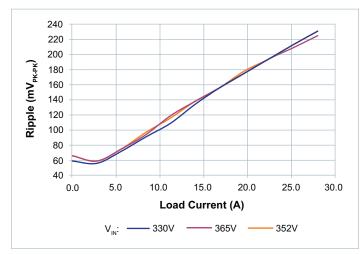


Figure 12 — V_{RIPPLE} vs. I_{OUT} : no external C_{OUT} , board-mounted module, scope setting: 20MHz analog BW

Application Characteristics (Cont.)

The following values, typical of an application environment, are collected at $T_{CASE} = 25$ °C unless otherwise noted. See associated figures for general trend data.

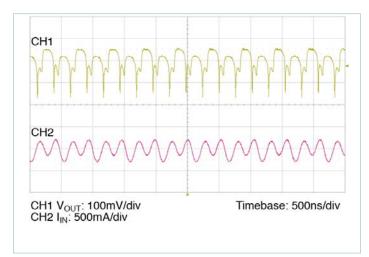


Figure 13 — Full-load ripple, 330μF C_{IN}: no external C_{OUT}, board-mounted module; scope setting: 20MHz analog BW

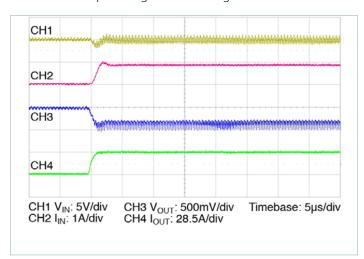


Figure 15 — 0 – 28.5A transient response: C_{IN} = 2.2 μ F, I_{IN} measured prior to C_{IN} , no external C_{OUT}

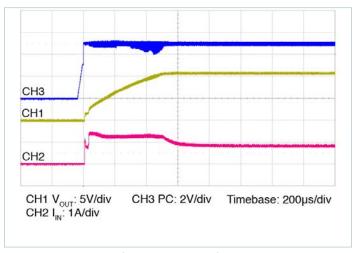


Figure 14 — Start up from application of PC; V_{IN} pre-applied $C_{OUT} = 4000 \mu F$

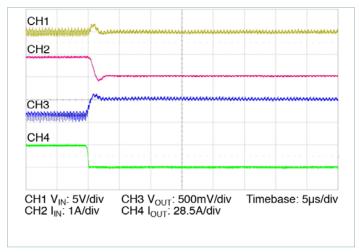


Figure 16 — 28.5 – 0A transient response: C_{IN} = 2.2 μ F, I_{IN} measured prior to C_{IN} , no external C_{OUT}

General Characteristics

Specifications apply over all line and load conditions, unless otherwise noted; **boldface** specifications apply over the temperature range of $-40^{\circ}\text{C} \leq T_{\text{CASE}} \leq 100^{\circ}\text{C}$ (T-Grade); All other specifications are at $T_{\text{CASE}} = 25^{\circ}\text{C}$ unless otherwise noted.

Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit	
		Mechanical					
Length	L		32.25 [1.270]	32.50 [1.280]	32.75 [1.289]	mm [in]	
Width	W		21.75 [0.856]	22.00 [0.866]	22.25 [0.876]	mm [in]	
Height	Н		6.48 [0.255]	6.73 [0.265]	6.98 [0.275]	mm [in]	
Volume	Vol	No heat sink		4.81 [0.294]		cm³ [in³]	
Weight	W			14.5 [0.512]		g [oz]	
		Nickel	0.51		2.03		
Lead Finish		Palladium	0.02		0.15	μm	
		Gold	0.003		0.051		
		Thermal					
Operating Temperature	т	BCM352F110T300B00 (T-Grade)	-40		125	°C	
Operating Temperature	TJ	BCM352F110M300B00 (M-Grade)	-55		125	30	
Thermal Resistance	θ_{JC}	Isothermal heat sink and isothermal internal PCB		1		°C/W	
Thermal Capacity				5		Ws/°C	
		Assembly					
Peak Compressive Force					6	lbs	
Applied to Case (Z-Axis)		Supported by J-lead only			5.41	lbs/ in ²	
C1 T	_	BCM352F110T300B00 (T-Grade)	-40		125	°C	
Storage Temperature	T _{ST}	BCM352F110M300B00 (M-Grade)	-55		125	°C	
FCD MULTINATION IN	ESD _{HBM}	Human Body Model, JEDEC JESD 22-A114D.01 Class 1C	2000			.,	
ESD Withstand	ESD _{CDM}	Charged Device Model, JEDEC JESD 22-C101-D	500			V	
		Soldering					
Deal. Terrarentum During Bellevi		RoHS			245	°C	
Peak Temperature During Reflow		Non-RoHS			225	30	
Peak Time Above Liquidus		Requires AN:009 compliance	60		90	S	
Peak Heating Rate During Reflow		Requires AN:009 compliance		1.5	3	°C/s	
Peak Cooling Rate Post Reflow		Requires AN:009 compliance		1.5	6	°C/s	
		Safety					
Working voltage (IN – OUT)	V_{IN_OUT}				500	V_{DC}	
Isolation Voltage (Hipot)	V _{HIPOT}		4242			V_{DC}	
Isolation Capacitance	C _{IN_OUT}	Unpowered unit	500	660	800	pF	
Isolation Resistance	R _{IN_OUT}	At 500V _{DC}	10			ΜΩ	
MTBF		MIL-HDBK-217Plus Parts Count - 25°C Ground Benign, Stationary, Indoors / Computer Profile		3.15		MHrs	
		Telcordia Issue 2 - Method I Case III; 25°C Ground Benign, Controlled		6.64		MHrs	
		cTÜVus					
Agency Approvals / Standards		cURus					
Agency Approvals / Standards		UKCA, electrical equipment (safety) regu	ulations				
		CE Marked for Low Voltage Directive an	d ROHS recast di	ective, as applic	able		



Using The Control Signals PC, TM

Primary Control (PC) pin can be used to accomplish the following functions:

- Logic enable and disable for module: Once t_{ON1} time has been satisfied, a PC voltage greater than V_{PC_EN} will cause the module to start. Bringing PC lower than V_{PC_DIS} will cause the module to enter standby.
- Auxiliary voltage source: Once enabled in regular operational conditions (no fault), each BCM module PC provides a regulated 5V, 3.5mA voltage source.
- Synchronized start up: In an array of parallel modules, PC pins should be connected to synchronize start up across units.
- **Output disable:** PC pin can be actively pulled down in order to disable the module. Pull-down impedance shall be lower than 60Ω .
- Fault-detection flag: The PC 5V voltage source is internally turned off as soon as a fault is detected.

Note that PC can not sink significant current during a fault condition. The PC pin of a faulted module will not cause interconnected PC pins of other modules to be disabled.

Temperature Monitor (TM) pin provides a voltage proportional to the absolute temperature of the converter control IC.

It can be used to accomplish the following functions:

- Monitor the control IC temperature: The temperature in Kelvin is equal to the voltage on the TM pin scaled by 100. (i.e., 3.0V = 300K = 27°C). If a heat sink is applied, TM can be used to protect the system thermally.
- Fault-detection flag: The TM voltage source is internally turned off as soon as a fault is detected. For system monitoring purposes microcontroller interface faults are detected on falling edges of TM signal.



Sine Amplitude Converter™ Point-of-Load Conversion

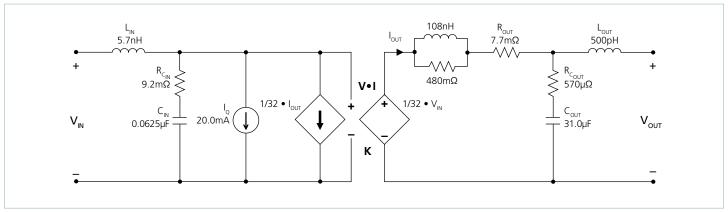


Figure 17 — VI Chip® module AC model

The Sine Amplitude Converter (SACTM) uses a high-frequency resonant tank to move energy from input to output. The resonant LC tank, operated at high frequency, is amplitude modulated as a function of input voltage and output current. A small amount of capacitance embedded in the input and output stages of the module is sufficient for full functionality and is key to achieving power density.

The BCM352x110y300B00 SAC can be simplified into the preceding model.

At no load:

$$V_{OUT} = V_{IN} \bullet K \tag{1}$$

K represents the "turns ratio" of the SAC. Rearranging Equation 1:

$$K = \frac{V_{OUT}}{V_{IN}} \tag{2}$$

In the presence of a load, V_{OUT} is represented by:

$$V_{OUT} = V_{IN} \bullet K - I_{OUT} \bullet R_{OUT}$$
 (3)

and I_{OUT} is represented by:

$$I_{OUT} = \frac{I_{IN} - I_Q}{K} \tag{4}$$

R_{OUT} represents the impedance of the SAC, and is a function of the R_{DS_ON} of the input and output MOSFETs and the winding resistance of the power transformer. I_Q represents the quiescent current of the SAC control, gate drive circuitry and core losses.

The use of DC voltage transformation provides additional interesting attributes. Assuming that $R_{OUT}=0\Omega$ and $I_Q=0A$, Equation 3 now becomes Equation 1 and is essentially load independent, resistor R is now placed in series with V_{IN} .

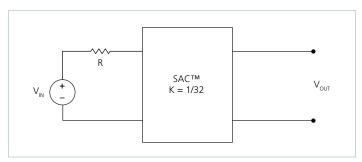


Figure 18 — K = 1/32 Sine Amplitude Converter with series input resistor

The relationship between V_{IN} and V_{OUT} becomes:

$$V_{OUT} = (V_{IN} - I_{IN} \bullet R) \bullet K \tag{5}$$

Substituting the simplified version of Equation 4 (I_Q is assumed = 0A) into Equation 5 yields:

$$V_{OUT} = V_{IN} \bullet K - I_{OUT} \bullet R \bullet K^2$$
 (6)

This is similar in form to Equation 3, where R_{OUT} is used to represent the characteristic impedance of the SAC. However, in this case a real R on the input side of the SAC is effectively scaled by K^2 with respect to the output.

Assuming that R = 1Ω , the effective R as seen from the secondary side is $1.0m\Omega$, with K = 1/32.

A similar exercise should be performed with the addition of a capacitor or shunt impedance at the input to the SAC. A switch in series with $V_{\rm IN}$ is added to the circuit. This is depicted in Figure 19.

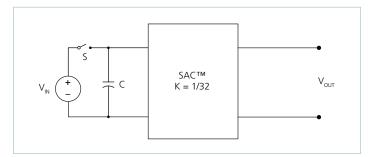


Figure 19 — Sine Amplitude Converter™ with input capacitor

A change in V_{IN} with the switch closed would result in a change in capacitor current according to the following equation:

$$I_C(t) = C \frac{dV_{IN}}{dt} \tag{7}$$

Assume that with the capacitor charged to V_{IN} , the switch is opened and the capacitor is discharged through the idealized SAC. In this case.

$$I_C = I_{OUT} \bullet K \tag{8}$$

substituting Equations 1 and 8 into Equation 7 reveals:

$$I_{OUT} = \frac{C}{K^2} \bullet \frac{dV_{OUT}}{dt} \tag{9}$$

The equation in terms of the output has yielded a K^2 scaling factor for C, specified in the denominator of the equation.

A K factor less than unity results in an effectively larger capacitance on the output when expressed in terms of the input. With a K = 1/32 as shown in Figure 19, C = 1μ F would appear as C = 1024μ F when viewed from the output.

Low impedance is a key requirement for powering a high-current, low-voltage load efficiently. A switching regulation stage should have minimal impedance while simultaneously providing appropriate filtering for any switched current. The use of a SAC between the regulation stage and the point-of-load provides a dual benefit of scaling down series impedance leading back to the source and scaling up shunt capacitance or energy storage as a function of its K factor squared. However, the benefits are not useful if the series impedance of the SAC is too high. The impedance of the SAC must be low, i.e., well beyond the crossover frequency of the system.

A solution for keeping the impedance of the SAC low involves switching at a high frequency. This enables small magnetic components because magnetizing currents remain low. Small magnetics mean small path lengths for turns. Use of low-loss core material at high frequencies also reduces core losses.

The two main terms of power loss in the BCM module are:

- No-load power dissipation (P_{NL}): defined as the power used to power up the module with an enabled powertrain at no load.
- Resistive loss (P_{ROUT}): refers to the power loss across the BCM modeled as pure resistive impedance.

$$P_{DISSIPATED} = P_{NL} + P_{ROUT} \tag{10}$$

Therefore,

$$P_{OUT} = P_{IN} - P_{DISSIPATED} = P_{IN} - P_{NL} - P_{ROUT}$$
 (11)

The above relations can be combined to calculate the overall module efficiency:

$$\eta = \frac{P_{OUT}}{P_{IN}} = \frac{P_{IN} - P_{NL} - P_{R_{OUT}}}{P_{IN}}$$
 (12)

$$= \frac{V_{\mathit{IN}} \bullet I_{\mathit{IN}} - P_{\mathit{NL}} - (I_{\mathit{OUT}})^2 \bullet R_{\mathit{OUT}}}{V_{\mathit{IN}} \bullet I_{\mathit{IN}}}$$

$$=1-\frac{\left(P_{\scriptscriptstyle NL}+\left(I_{\scriptscriptstyle OUT}\right)^2\bullet R_{\scriptscriptstyle OUT}\right)}{V_{\scriptscriptstyle IN}\bullet I_{\scriptscriptstyle IN}}$$

Input and Output Filter Design

A major advantage of SACTM systems versus conventional PWM converters is that the transformers do not require large functional filters. The resonant LC tank, operated at extreme high frequency, is amplitude modulated as a function of input voltage and output current and efficiently transfers charge through the isolation transformer. A small amount of capacitance embedded in the input and output stages of the module is sufficient for full functionality and is key to achieve power density.

This paradigm shift requires system design to carefully evaluate external filters in order to:

■ Guarantee low source impedance:

To take full advantage of the BCM's dynamic response, the impedance presented to its input terminals must be low from DC to approximately 5MHz. The connection of the bus converter module to its power source should be implemented with minimal distribution inductance. If the interconnect inductance exceeds 100nH, the input should be bypassed with a RC damper to retain low source impedance and stable operation. With an interconnect inductance of 200nH, the RC damper may be as high as $1\mu F$ in series with 0.3Ω . A single electrolytic or equivalent low-Q capacitor may be used in place of the series RC bypass.

Further reduce input and/or output voltage ripple without sacrificing dynamic response:

Given the wide bandwidth of the module, the source response is generally the limiting factor in the overall system response. Anomalies in the response of the source will appear at the output of the module multiplied by its K factor. This is illustrated in Figures 15 and 16.

Protect the module from overvoltage transients imposed by the system that would exceed maximum ratings and cause failures:

The module input/output voltage ranges shall not be exceeded. An internal overvoltage lockout function prevents operation outside of the normal operating input range. Even during this condition, the powertrain is exposed to the applied voltage and power MOSFETs must withstand it. A criterion for protection is the maximum amount of energy that the input or output switches can tolerate if avalanched.

Total load capacitance at the output of the BCM shall not exceed the specified maximum. Owing to the wide bandwidth and low output impedance of the module, low-frequency bypass capacitance and significant energy storage may be more densely and efficiently provided by adding capacitance at the input of the module. At frequencies <500kHz the module appears as an impedance of ROLIT between the source and load.

Within this frequency range, capacitance at the input appears as effective capacitance on the output per the relationship defined in Equation 13.

$$C_{OUT} = \frac{C_{IN}}{K^2} \tag{13}$$

This enables a reduction in the size and number of capacitors used in a typical system.

Thermal Considerations

VI Chip® products are multi-chip modules whose temperature distribution varies greatly for each part number as well as with the input / output conditions, thermal management and environmental conditions. Maintaining the top of the BCM352x110y300B00 case to less than 100°C will keep all junctions within the VI Chip module below 125°C for most applications.

The percent of total heat dissipated through the top surface versus through the J-lead is entirely dependent on the particular mechanical and thermal environment. The heat dissipated through the top surface is typically 60%. The heat dissipated through the J-lead onto the PCB surface is typically 40%. Use 100% top surface dissipation when designing for a conservative cooling solution.

It is not recommended to use a VI Chip module for an extended period of time at full load without proper heat sinking.



Current Sharing

The performance of the SACTM topology is based on efficient transfer of energy through a transformer without the need of closed loop control. For this reason, the transfer characteristic can be approximated by an ideal transformer with a positive temperature coefficient series resistance.

This type of characteristic is close to the impedance characteristic of a DC power distribution system both in dynamic (AC) behavior and for steady state (DC) operation.

When multiple BCM modules of a given part number are connected in an array they will inherently share the load current according to the equivalent impedance divider that the system implements from the power source to the point of load.

Some general recommendations to achieve matched array impedances include:

- Dedicate common copper planes within the PCB to deliver and return the current to the modules.
- Provide as symmetric a PCB layout as possible among modules
- Apply same input / output filters (if present) to each unit.

For further details see <u>AN:016 Using BCM Bus Converters in High Power Arrays.</u>

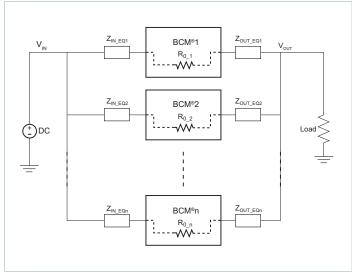


Figure 19 — BCM module array

Fuse Selection

In order to provide flexibility in configuring power systems VI Chip® modules are not internally fused. Input line fusing of VI Chip products is recommended at system level to provide thermal protection in case of catastrophic failure.

The fuse shall be selected by closely matching system requirements with the following characteristics:

- Current rating (usually greater than maximum current of BCM module)
- Maximum voltage rating (usually greater than the maximum possible input voltage)
- Ambient temperature
- Nominal melting I²t
- Recommend fuse: ≤ 2.5A Bussmann® PC-Tron® or ≤ 3.15A SOC type 36CFA.

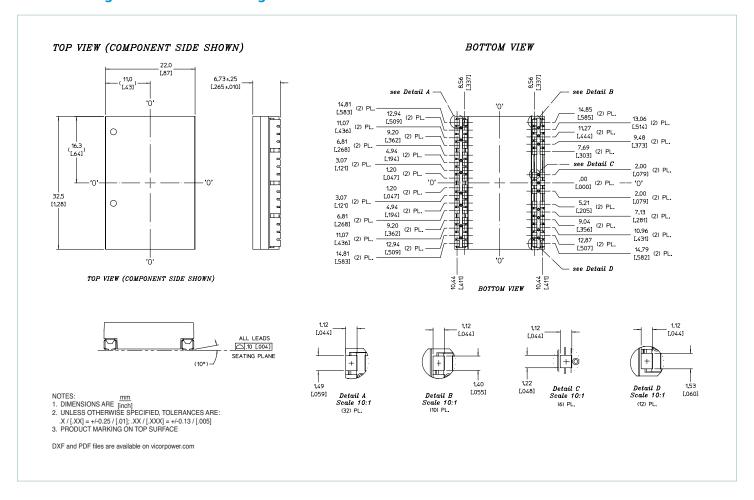
Reverse Operation

BCM modules are capable of reverse power operation. Once the unit is started, energy will be transferred from secondary back to the primary whenever the secondary voltage exceeds $V_{\text{IN}} \bullet K$. The module will continue operation in this fashion for as long as no faults occur.

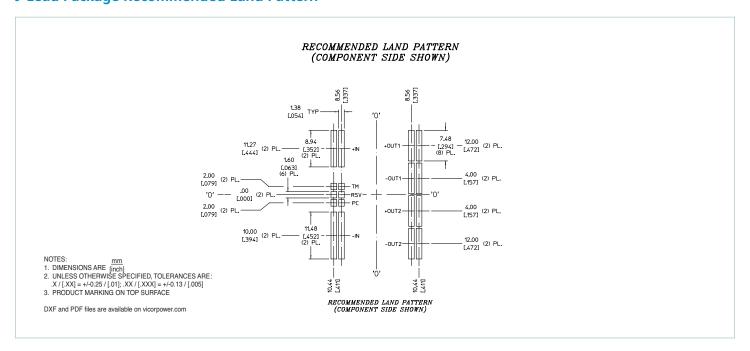
The BCM352x110y300B00 has not been qualified for continuous operation in a reverse power condition. Furthermore fault protections which help protect the module in forward operation will not fully protect the module in reverse operation.

Transient operation in reverse is expected in cases where there is significant energy storage on the output and transient voltages appear on the input. Transient reverse power operation of less than 10ms, 10% duty cycle is permitted and has been qualified to cover these cases.

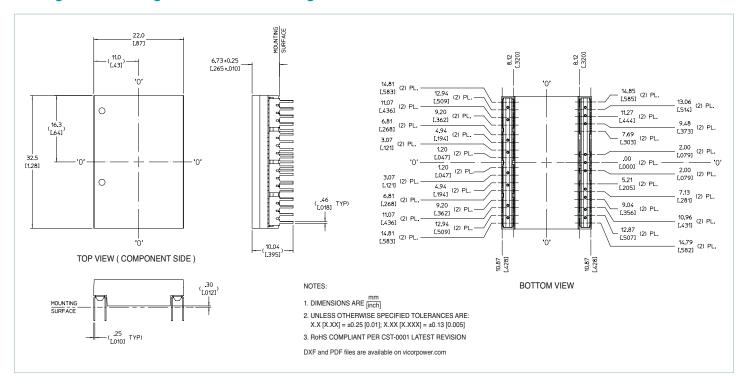
J-Lead Package Mechanical Drawing



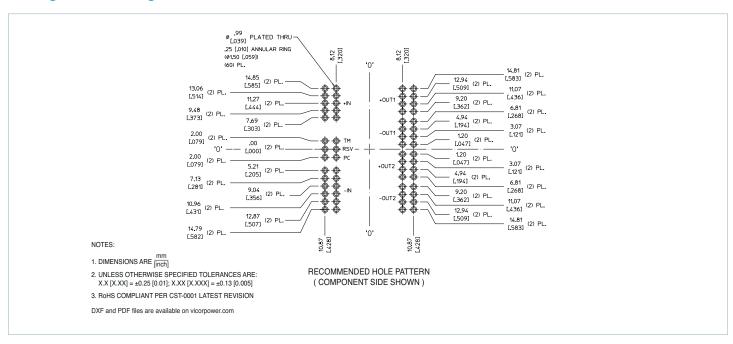
J-Lead Package Recommended Land Pattern



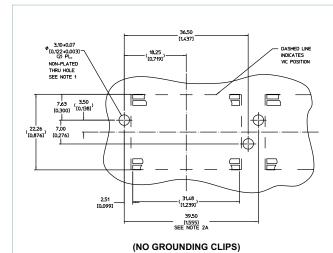
Through-Hole Package Mechanical Drawing

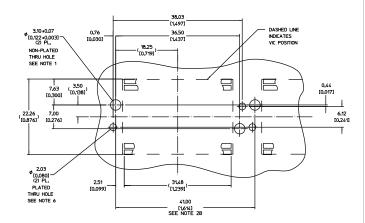


Through-Hole Package Recommended Land Pattern



Recommended Heat Sink Push Pin Location





(WITH GROUNDING CLIPS)

Notes:

- Maintain 3.50 [0.138] Dia. keep-out zone free of copper, all PCB layers.
- 2. (A) Minimum recommended pitch is 39.50 (1.555). This provides 7.00 [0.275] component edge-to-edge spacing, and 0.50 [0.020] clearance between Vicor heat sinks.

 (B) Minimum recommended pitch is 41.00 [1.614].
 - (B) Minimum recommended pitch is 41.00 [1.614]. This provides 8.50 [0.334] component edge-to-edge spacing, and 2.00 [0.079] clearance between Vicor heat sinks.
- VI Chip® module land pattern shown for reference only; actual land pattern may differ.
 Dimensions from edges of land pattern to push–pin holes will be the same for all full-size VI Chip® products.
- 4. RoHS compliant per CST-0001 latest revision.
- 5. Unless otherwise specified:
 Dimensions are mm [inches]
 tolerances are:
 x.x (x.xx) = ±0.3 [0.01]
 x.xx (x.xxx) = ±0.13 [0.005]
- Plated through holes for grounding clips (33855) shown for reference, heat sink orientation and device pitch will dictate final grounding solution.

Revision History

Revision	Date	Description	Page Number(s)
1.3	06/05/24	Updated agency approvals, soldering specification Updated P_{NL} , η_{AMB} , R_{OUT_COLD} , R_{OUT_AMB}	1, 12 3



Vicor's comprehensive line of power solutions includes high density AC-DC and DC-DC modules and accessory components, fully configurable AC-DC and DC-DC power supplies, and complete custom power systems.

This is not an offer to sell any products. Any potential future offers to sell shall be conditioned upon Vicor's Standard Terms and Conditions of Sale and Vicor's Express Limited Warranty, which are available at www.vicorpower.com.

Warranty

THE PRODUCTS REFERRED TO HEREIN ARE PRE-RELEASE PRODUCTS. ALL INFORMATION IS PROVIDED "AS IS", AND VICOR DISCLAIMS ANY AND ALL WARRANTIES, WHETHER EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT, TO THE EXTENT AUTHORIZED BY LAW. WITHOUT LIMITATION OF THE FOREGOING, VICOR EXPRESSLY DISCLAIMS ANY WARRANTY THAT THE PRODUCTS WILL MEET YOUR REQUIREMENTS OR THAT ANY RELEASED PRODUCT WILL BE AS DESCRIBED HEREIN, AVAILABLE FOR PURCHASE WITHIN ANY STATED TIME FRAME OR WILL BE RELEASED BY VICOR AT ANY TIME.

THE DOCUMENTATION IS CONFIDENTIAL AND PROPRIETARY TO VICOR. YOU AGREE THAT YOU WILL NOT DUPLICATE OR DISCLOSE THIS DOCUMENTATION OR THE INFORMATION CONTAINED HEREIN WITHOUT THE EXPRESS WRITTEN CONSENT OF VICOR. TO OBTAIN SUCH CONSENT OR TO INFORM VICOR OF ANY SUCH DISCLOSURE, PLEASE CONTACT VICOR AT THE ADDRESS OR EMAIL BELOW.

Life Support Policy

VICOR'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER OF VICOR CORPORATION. As used herein, life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness. Per Vicor Standard Terms and Conditions of Sale, the user of Vicor products and components in life support applications assumes all risks of such use and indemnifies Vicor against all liability and damages.

Intellectual Property Notice

Vicor and its subsidiaries own Intellectual Property (including issued U.S. and pending patent applications) relating to the products described in this data sheet. No license, whether express, implied, or arising by estoppel or otherwise, to any intellectual property rights is granted by this document. Interested parties should contact Vicor's Intellectual Property Department.

Contact Us: https://www.vicorpower.com/contact-us

Vicor Corporation

25 Frontage Road Andover, MA, USA 01810 Tel: 800-735-6200 Fax: 978-475-6715 www.vicorpower.com

email

Customer Service: <u>custserv@vicorpower.com</u> Technical Support: <u>apps@vicorpower.com</u>

©2024 Vicor Corporation. All rights reserved. The Vicor name is a registered trademark of Vicor Corporation.

Bussmann® and PC-Tron® are registered trademarks of Eaton.

SOC is a registered trademark of SOC Corporation.

All other trademarks, product names, logos and brands are property of their respective owners.

